

# **FET Driver with Programmable Slew Rate**

### **Preliminary Technical Data**

ADM1200

#### **FEATURES**

Enables Power Supply Tracking of multiple supplies
Capacitor Adjustable Linear Slew Rate
On Board Charge Pump Fully enhances NFET
Up/Down slew rate control to approx. +/-100mV
Ability to Track Down Supplies (ADM1200-1)
Emergency Shutdown Feature (ADM1200-2)
Packaged in tiny 6-Lead SOT-23 Package

#### **APPLICATIONS**

Multi-Voltage Supply Rail Tracker Telecoms and Datacoms Systems Multi voltage Network Processors , FPGAs, ASICs, DSPs PC/Server Applications

#### **GENERAL DESCRIPTION**

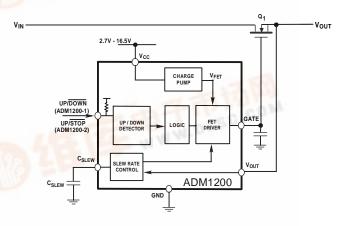
The ADM1200 is FET driver capable of driving N channel FETs. Is features a capacitor programmable SLEW rate control system ensuring that the output voltage rises and falls at a controlled rate and in a linear fashion. The ADM1200 is designed to ensure that the output voltage follows the voltage on the SLEW pin to within ~100mV. It can also be cascaded to perform simple tracking functionality of supply rails ensuring that each voltage rails track within ~100mV of each other in multi supply systems. Any number of these devices can be cascaded to form a multi supply tracking solution.

The ADM1200 requires 2.7V to 16.5V on its Vcc pin to operate. An on-board charge pump generates a high voltage GATE drive to fully enhance FETs in the power path.

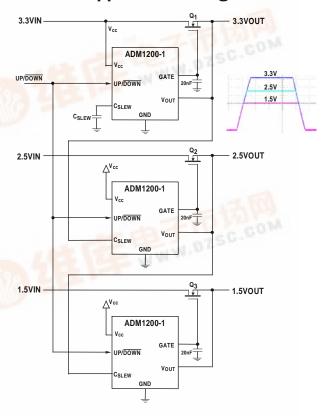
The Slew Rate of the ramp is adjustable via an external capacitor on the  $C_{SLEW}$  pin and can be programmed from 100V/s to 1000V/s. When multiple devices are cascaded the  $C_{SLEW}$  pin of each subsequent device should be tied to the output rail( $V_{OUTFB}$ ) of the previous device to ensure that supply will slew up and down with the previous supply.

The ADM1200 is offered in two variants. The ADM1200-1 features an UP/DOWNb pin and the ADM1200-2 features an Up/STOPb pin. For both devices a high level on the this input will initiate tracking up sequence. A low on the UP/DOWNb pin of the ADM1200-1 will initiate a tracking down of the supply rails, while a low on the UP/STOPb pin of the ADM1200-2 will initiate an emergency fast shutdown of all supply rails simultaneously. The ADM1200 is packaged in a tiny 6-pin SOT-23 package.

### **Functional Block Diagram**



### **Applications Diagram**



Reverphore
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## ADM1200—SPECIFICATIONS

Table 1.  $V_{cc}$  = Full Operating Range,  $T_A$  = -40°C to +105°C, unless otherwise noted.

Parameter	Min	Тур	Max	Units	Conditions	
V <sub>cc</sub> Pin						
Operating Voltage Range Vcc	2.7		16.5	V		
Undervoltage Lockout, V <sub>UVLO</sub>	2.4	2.525	2.65	٧	Vcc Rising	
UVLO Hysteresis		25		mV		
Switched Voltage Range	0.65		16.5	V		
Quiesent Current		0.5	1.5	mA		
Up/Downb Pin						
Input Threshold	0.6	0.63	0.66	V	Rising	
Input Threshold Hysteresis		60		mV		
Input Current	-100		100	nA		
C <sub>SLEW</sub> Pin						
Slew up Current		-10		μA		
Slew down Current		10		μA		
Slew Gain		1		V/V	V <sub>SLEW</sub> /V <sub>OUTFB</sub>	
Minimum Tracking Voltage		0.1		V		
Maximum Tracking voltage		Vcc – 0.3		V		
Tracking Delta		100		mV	V <sub>OUTFB</sub> - V <sub>SLEW</sub>	
Slew Rate	100		1000	V/s		
V <sub>OUTFB</sub> Pin						
Input Current	-12		12	μA		
Voltage Range	0		Vcc	V	Must not exceed V <sub>CC</sub>	
GATE Pin						
Gate Pullup Current		10		μA	Vslew – Vout > 100mV	
Gate Pulldown Current		12		μΑ	Vout – Vslew > 100mV	
Gate Pulldown Current		2		mA	ADM1200-2 only; vgate = 3.0\	
GATE Voltage, V <sub>GATE</sub>	4	5.5	8	V	$V_{GATE} - V_{CC}$ ; $V_{CC} = 2.7V$	
	6	8	10	V	$V_{GATE} - V_{CC}$ ; $V_{CC} = 3.3V$	
	8	10	12	V	$V_{GATE} - V_{CC}$ ; $V_{CC} = 5.0V$	
	6	8	12	٧	$V_{GATE} - V_{CC}$ ; $V_{CC} = 16.5V$	

## **Absolute Maximum Ratings**

**Table 2. ADM1200 Absolute Maximum Ratings** 

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Parameter	Rating				
V <sub>CC</sub> Pin	-0.3V to 20V				
UP/DOWNb, UP/STOPb	-0.3V to 20V				
C <sub>SLEW</sub> Pin	-0.3V to 20V				
Gate Pin	-0.3V to (V <sub>CC</sub> + 11V)				
V <sub>OUTFB</sub> Pin	-0.3V to (V <sub>CC</sub> + 0.3V)				
Power Dissipation	TBD				
Storage Temperature	−65°C to +125°C				
Operating Temperature Range	-40°C to +105°C				
Lead Temperature Range	300°C				
(Soldering 10 sec)					
Junction Temperature	150°C				

#### **GENERAL INFORMATION**

The ADM1200 provides a solution for slew rate control, linear supply regulation and voltage tracking. The device requires a supply voltage of 2.7V to 16.5V on its Vcc pin for operation. The device may be powered from the input supply rail that is being switched or from an auxiliary supply providing it does not exceed the voltage to be expected on the devices  $V_{\text{OUTFB}}$  pin.

#### **GATE**

An internal charge pump ensures that the ADM1200 is capable of fully enhancing an external N channel FET via the GATE pin. An external capacitor may be required on the GATE node for stability. During under voltage lockout the GATE pin is held low to avoid any glitches on the FETs gate and prevent false power ups.

#### **SLEW**

The value of the slew rate capacitor,  $C_{SLEW}$ , will dictate the slew rate of the output voltage. An internal current source charges  $C_{SLEW}$  in a linear fashion and the GATE voltage is controlled so that  $V_{OUT}$  will be regulated to within 100mV from  $V_{SLEW}$ . The maximum voltage that the ADM1200 can control is 0.3V below Vcc. Once the SLEW pin reaches this maximum voltage the GATE is driven fully high.

The C<sub>SLEW</sub> capacitor is determined by:

 $C_{SLEW} = 10\mu A / Slewrate(V/s)$ 

On the ADM1200-2 only, a high to low on the UP/DOWN pin will enable a current sink on the SLEW pin to discharge the capacitor at the same rate. This will initiate a SLEW down of the output.

#### **VOUTFB**

The  $V_{\text{OUTFB}}$  pin monitors the output voltage to ensure it is kept within approximately 100mV of the voltage on the SLEW pin. This pin must not exceed the Vcc voltage at any time or it may cause damage to the device.

#### **UP/DOWN AND UP/STOP**

Power up can be externally initiated by driving the UP/DOWNb (ADM1200-1) or UP/STOPb (ADM1200-2) logic pin high. A low on the ADM1200-1 will initiate a track down and one the ADM1200-2 the gate will shutdown immediately. This is illustrated in Figure 1 and Figure 2.

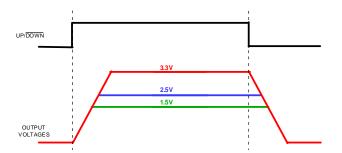


Figure 1. ADM1200-1 Power-Up and Power-Down Waveforms

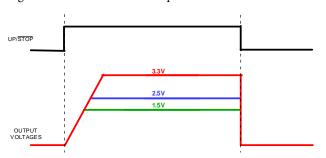


Figure 2. ADM1200-2 Power-Up and Power-Down Waveforms

#### **ENABLING A SINGLE SUPPLY**

A single ADM1200 device may be used where a single supply rail is required to switch on at a controlled linear slew rate (see Figure 3). The capacitor  $C_{\text{SLEW}}$  determines the slew rate

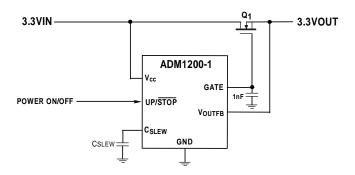


Figure 3. ADM1200 Switching on a Single Supply

#### **MULTI-SUPPLY TRACKING**

The ADM1200 can be used to provide a voltage tracking solution for multiple supply rails. The implementation in Figure 4 will provide this function. Each voltage rail has its own ADM1200 device driving a FET.

The UP/DOWNb (ADM1200-1) or UP/STOPb (ADM1200-2) pins of all devices can be driven by a single logic input which will initiate a system power-up going high or power-down going low.

In Figure 4, the ADM1200 is configured to control the ramp of the largest supply first. The output of the first device is

connected to the slew pin on the second device to allow the rate of the first supply to control the rate of the second and so on.

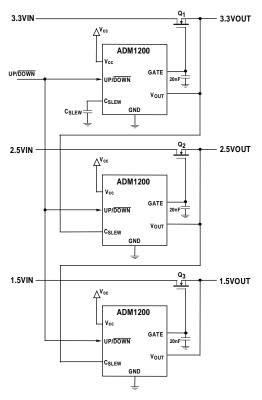


Figure 4. . ADM1200 Solution for Tracking 3 Supplies

A low-to-high transition on the UP/DOWNb or UP/STOPb pin will initiate turn-on of the supplies. The first ADM1200 device will begin to source current into the C<sub>SLEW</sub> capacitor. This will bring up the Gate in an attempt to ensure the output voltage will follow the SLEW voltage The output voltage is monitored using V<sub>OUTFB</sub> pin. The output will then track the SLEW voltage on this device. Figure 5 shows an actual plot of two supplies tracking up. The output of this first supply is then fed into the SLEW pin of the next ADM1200. This will overdrive the slew current on this device. The second ADM1200 will then ensure that the output of the second supply will track up/down along with the output from the first. Any number of ADM1200 devices can be cascaded in this way. Figure 5 and Figure 6 show actual waveforms of the output voltages for ADM1200-1 and ADM1200-2 devices in this configuration.

A high-to-low on the UP/DOWNb pin of the ADM1200-1 will initiate a tracking down of the supply rails. The voltages will attempt to stay with  $\sim \! 100 \mathrm{mV}$  of each other assuming the load current will be sufficient to discharge the capacitors at the required rate. During a high to low on the UP/STOPb pin, the ADM1200-2 device will pull the GATE to the FET low immediately but the output voltage will only fall at a rate determined by the load capacitance and impedance.

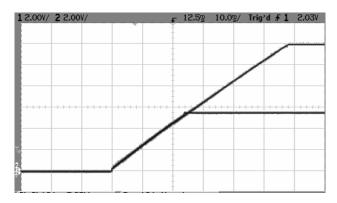


Figure 5. Tracking up Waveforms

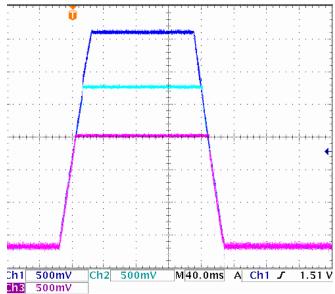


Figure 6 ADM1200-1Track up and Track down.

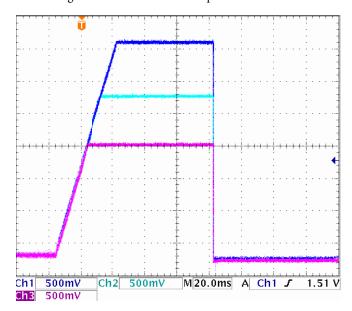
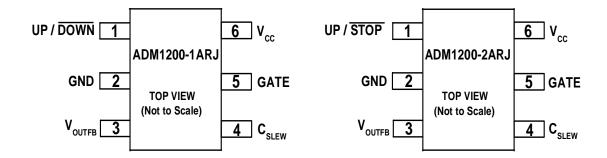


Figure 7. ADM1200-2 Track up and stop.

## PIN CONFIGURATIONS



## PIN FUNCTIONAL DESCRIPTIONS

Pin No.	Name	Description
1	UP/DOWNb or UP/STOPb	Logic Pin. Drive high to initiate slew up. Drive low to initiate slew down of output (ADM1200-1) or a fast shutdown of output (ADM1200-2).
2	GND	Chip Ground Pin.
3	VOUTFB	Monitors the output voltage at the source of the external FET. Must not exceed Vcc.
4	CSLEW	Connect to an external capacitor to control the slew rate of the output for power up (and power down for ADM1200-1).
5	GATE	Drives the GATE node of the external FET
6	VCC	Chip Power Supply, 2.7V to 16.5V. Recommended decoupling cap of 100nF

### **OUTLINE DIMENSIONS**

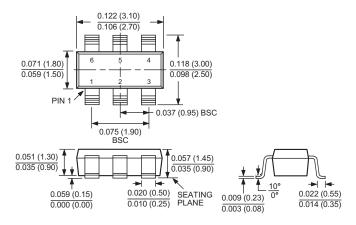


Figure 5. 6-Lead SOT-23 Package (RJ-6)—Dimensions shown in millimeters

#### **ESD CAUTION**

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



**Table 3. Ordering Guide** 

Model	Temperature Range	Package Description	Package Option	Branding
ADM1200-1WRJZ-RL7	−40°C to +105°C	8-Lead TSOT	RJ-6	M1S
ADM1200-2WRJZ-RL7	-40°C to +105°C	8-Lead TSOT	RJ-6	M1U





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